Claims

- A tunnel diode comprising:
 - (a) an emitter electrode, in contact with
 - (b) a porous material, in contact with
- 5 (c) a collector electrode

wherein said porous material has a thickness which is less then the free mean free path of an electron in said porous material.

- 2. The tunnel diode of claim 1 in which said porous material comprises porous silicon.
- 10 3. The tunnel diode of claim 1 in which said porous material comprises doped porous silicon.
 - 4. The tunnel diode of claim 1 in which said thickness is in the range of 1 to 100 nm.
- The tunnel diode of claim 1 additionally comprising a heat source in
 contact with said emitter electrode.
 - 6. The tunnel diode of claim 1 additionally comprising a heat sink in contact with said collector electrode.
 - 7. Apparatus for the conversion of energy comprising:
 - (a) a source of energy;

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- (b) an emitter electrode connected to said source of energy;
 - (c) a collector electrode;
 - (d) a porous material disposed between said emitter electrode and said collector electrode;
- (e) an electrical circuit connecting said electrodes; and
 wherein said porous material has a thickness which is less then the free mean free path of an electron in said porous material.
 - 8. The apparatus of claim 7 in which said porous material comprises porous silicon.
- The apparatus of claim 7 in which said porous material comprises doped
 porous silicon.

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- 10. The apparatus of claim 7 in which said thickness is in the range of 1 to 100 nm.
- 11. The apparatus of claim 7, wherein the conversion of energy is the conversion of thermal energy to electrical energy, wherein said source of energy comprises a source of thermal energy, and wherein said apparatus further comprises:

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- a) a first thermal interface thermally connecting said source of energy to said emitter electrode;
- a second thermal interface thermally connecting a heat sink means to said collector electrode;
- c) an electrical load, electrically connected by said circuit between said collector electrode and said emitter electrode.
- 12. The apparatus of claim 11 wherein said source of thermal energy is of solar origin.
- 15 13. The apparatus of claim 7, wherein the conversion of energy is the conversion of electrical energy to heat pumping capacity, and wherein said apparatus further comprises:
 - a heat source and a heat sink, wherein said heat source is thermally connected to said emitter electrode and said heat sink is thermally connected to said collector electrode, and,
 - b) an electrical power supply, electrically connected by said circuit between said collector electrode and said emitter electrode for applying a voltage bias to said electrodes, said electrical power supply providing said energy source.
- 25 14. The apparatus of claim 13 wherein said heat source may be cooler than said heat sink.